

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	847	365/185.17.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:23
L2	1886	365/185.18.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:23
L3	156	L1 and L2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:23
L4	2	L3 and (select\$3 near3 string) same ((nonselect\$3 non-select\$3 deselect\$3 de-select\$3) near3 cell)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:23
L5	19	L1 and ((selected addressed) near3 (string wordline (word adj line) word line row) with (first adj3 (bias potential volt\$3))) same ((unselected un-selected nonselected non-selected deselected de-selected) near3 (cell bitline digitline (bit adj line) (digit adj line))) same program\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:23
L6	29	L3 and (program\$5 near3 (inadvert\$5 disturb\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:24
L7	972	365/185.28.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:24

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L8	25	L3 and L7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:24
L9	9	L6 and L8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:24
L10	847	365/185.17.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:25
L11	1886	365/185.18.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:25
L12	156	L10 and L11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:25
L13	10	L12 and ((program\$5 writ\$3) near3 stress\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:25
L14	847	365/185.17.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:26
L15	176	L14 and ((select\$3 address\$3) adj3 (string wordline (word adj line) word line row)) same ((unselect\$3 un-select\$3 nonselect\$3 non-select\$3 deselect\$3 de-select\$3) adj3 (cell bitline digitline (bit adj line) (digit adj line))) same program\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:26

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L16	4	L15 and L13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:26
L17	847	(365/185.17).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:28
L18	303	(365/185.02).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:28
L19	33	L17 and L18	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:28
L20	4	L19 and ((program\$5 writ\$3) with stress\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:28
L21	4	L15 and L13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:37
L22	847	365/185.17.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:39
L23	1886	365/185.18.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:39

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L24	156	L22 and L23	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:39
L25	4	L24 and (((program\$5 writ\$3) near3 stress\$3) same ((select\$3 address\$3) adj3 (cell bitline digitline (bit adj line) (digit adj line))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:39
L26	1092	(nonvolatile (non adj volatile)) and (nanoparticle (nano adj particle))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:39
L27	68	L26 and ("365"/\$5).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:39
L28	39	L27 and flash	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:39
L29	15	L27 and (two near5 bit near5 cell)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:39
L31	97	(nand adj3 string) and (((select\$3 access\$3) near3 (switch transistor)) near3 (float\$3 adj3 gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:40
L32	0	L31 and (cell near3 (thin adj3 film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:40

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L33	0	L31 and (cell with (thin adj3 film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:41
L34	17	L31 and ((thin adj3 film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:41
L35	0	((nand adj3 string) and (half near3 select\$3) and (bank block array) and ((wordline (word adj line)) near3 (program\$4 near3 (bias potential volt\$3))) and ((unselected nonselected) near3 string) and (turn\$3 adj3 on) and (turn\$3 adj3 off) and (array near3 line)).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:41
L36	3	365/185.02.ccls. and 365/185.28.ccls. and 365/230.03.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:42
L37	742	(nonvolatile (non adj volatile) flash EEPROM) and (nand near3 string)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:42
L38	209259	(ONO SONO (storage near3 dielectric) (oxide near3 nitride near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:42
L39	306	L37 and L38	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:42
L40	123	365/185.02.ccls. and (365/185.18.ccls. 365/185.28.ccls.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:42

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L41	4	L39 and L40	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:42
L42	1	L39 and L36	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:43
L43	1	(((nand adj string) with series) and ((half adj select\$3) with channel) and (((word adj line) wordline)) with (program\$4 near3 (volt\$3 bias potential)) and ((bitline (bit adj line)) with (inhibit\$3 near3 (bias potential volt\$3))) and (unselect\$3 near3 string) and coupl\$3 and (decoupl\$3 (de-coupl\$3))).clm.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/07 10:48